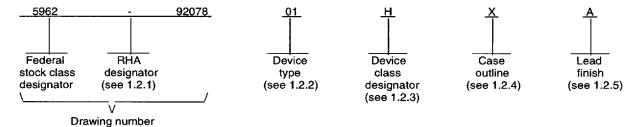
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F T fr ty	Table rom 2 ypes	I; Ch	DESCRIPTION									}	DATE (YR-MO-DA)			A)	APPROVED		. 1	
		ble I; Changed the max limit for I _{CC} for device types 06 through 09 m 200 mA to 210 mA. Changed the max limit for I _{CCDR} for device es 06 through 09 from 10.4 mA to 12.8 mA sld										09 ice		98-0	6-23 K. A. Cottongim			m		
REV						1										<u> </u>				
SHEET																-				
REV	F	F	F	F																
SHEET 1	15	16	17	18																
REV STATUS OF SHEETS				RE	/		F	F	F	F	F	F	F	F	F	F	F	F	F	F
OF SHEETS				SHE	EET		1	2	3	4	5	6	7	8	9	10	11	12	13	14
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	F SHEET 1 OF 18																			

<u>DISTRIBUTION STATEMENT A</u>. Approved for public release; distribution is unlimited.

5962-E401-98

1. SCOPE

- 1.1 <u>Scope</u>. This drawing documents five product assurance classes, class D (lowest reliability), class E, (exceptions), class G (lowest high reliability), class H (high reliability), and class K, (highest reliability) and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of radiation hardness assurance levels are reflected in the PIN.
 - 1.2 PIN. The PIN shall be as shown in the following example:



- 1.2.1 <u>Radiation hardness assurance (RHA) designator</u>. Device classes H and K RHA marked devices shall meet the MIL-PRF-38534 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
 - 1.2.2 Device type(s). The device type(s) shall identify the circuit function as follows:

Device type	Generic number	Circuit function	Access time	
01	WS512K8-120CQ	SRAM, 512K x 8-bit	120 ns	
02	WS512K8-100CQ	SRAM, 512K x 8-bit	100 ns	
03	WS512K8-85CQ	SRAM, 512K x 8-bit	85 ns	
04	WS512K8-70CQ	SRAM, 512K x 8-bit	70 ns	
05	WS512K8-55CQ	SRAM, 512K x 8-bit	55 ns	
06	WS512K8-45CQ	SRAM, 512K x 8-bit	45 ns	
07	WS512K8-35CQ	SRAM, 512K x 8-bit	35 ns	
08	WS512K8-25CQ	SRAM, 512K x 8-bit	25 ns	
09	WS512K8-20CQ	SRAM, 512K x 8-bit	20 ns	

1.2.3 <u>Device class designator</u>. This device class designator shall be a single letter identifying the product assurance level as follows:

Device class

Device performance documentation

D, E, G, H, or K

Certification and qualification to MIL-PRF-38534

1.2.4 Case outline(s). The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
Т	See figure 1	32	Duat-in-line, single cavity
Χ	See figure 1	32	Dual-in-line, dual cavity
Y	See figure 1	32	Dual-in-line, dual cavity, gull wing leads

1.2.5 Lead finish. The lead finish shall be as specified in MIL-PRF-38534.

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1.3 Absolute maximum ratings. 1/										
Supply voltage range (V _{CC}) Signal voltage range (any pin) Power dissipation (P _D) Storage temperature range Lead temperature (soldering, 10 seconds)	1 W 65°C t	dc to +7.0 V dc dc to +7.0 V dc o +150°C								
1.4 Recommended operating conditions.										
Supply voltage range (V _{CC}) Input low voltage range (V _{II}) Input high voltage range (V _{IH}) Output low voltage, maximum (V _{OL}) Output high voltage, minimum (V _{OH}) Case operating temperature range (T _C)	+4.5 V 0.5 V c +2.2 V +0.4 V +2.4 V 55°C t									
2. APPLICABLE DOCUMENTS										
2.1 Government specification, standards, and handbook. The following specification, standards, and handbook form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DoDISS) and supplement thereto, cited in the solitation.										
SPECIFICATION										
DEPARTMENT OF DEFENSE										
MIL-PRF-38534 - Hybrid Microcircuits, General Specification for.										
STANDARDS										
DEPARTMENT OF DEFENSE										
MIL-STD-883 - Test Methods and Procedures for Microman Miles - Configuration Management. MIL-STD-1835 - Microcircuit Case Outlines.	roelectronics.									
HANDBOOK										
DEPARTMENT OF DEFENSE										
MIL-HDBK-780 - Standard Microcircuit Drawings.										
(Unless otherwise indicated, copies of the specification, stand Document Order Desk, 700 Robbins Avenue, Building 4D, Phila	lards, and handbo delphia, PA 1911	ok are available from the S 1-5094.)	itandardization							
2.2 Order of precedence. In the event of a conflict between t of this drawing takes precedence. Nothing in this document, ho specific exemption has been obtained.	he text of this draw wever, supersede	wing and the references cites applicable laws and regu	ed herein, the text lations unless a							
1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.										
STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92078							
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL F	SHEET 3							

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3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item performance requirements for device classes D, E, G, H, and K shall be in accordance with MIL-PRF-38534. Compliance with MIL-PRF-38534 may include the performance of all tests herein or as designated in the device manufacturer's Quality Management (QM) plan or as designated for the applicable device class. Therefore, the tests and inspections herein may not be performed for the applicable device class (see MIL-PRF-38534). Futhermore, the manufacturers may take exceptions or use alternate methods to the tests and inspections herein and not perform them. However, the performance requirements as defined in MIL-PRF-38534 shall be met for the applicable device class.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38534 and herein.
 - 3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein and figure 1.
 - 3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.
 - 3.2.3 Truth table(s). The truth table(s) shall be as specified on figure 3.
 - 3.2.4 <u>Timing diagram(s)</u>. The timing diagram(s) shall be as specified on figures 4 and 5.
 - 3.2.5 Block diagram. The block diagram shall be as specified on figure 6.
 - 3.2.6 Output load circuit. The output load circuit shall be as specified on figure 7.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full specified operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.
- 3.5 <u>Marking of Device(s)</u>. Marking of device(s) shall be in accordance with MIL-PRF-38534. The device shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's vendor similar PIN may also be marked as listed in QML-38534.
- 3.6 <u>Data</u>. In addition to the general performance requirements of MIL-PRF-38534, the manufacturer of the device described herein shall maintain the electrical test data (variables format) from the initial quality conformance inspection group A lot sample, for each device type listed herein. Also, the data should include a summary of all parameters manually tested, and for those which, if any, are guaranteed. This data shall be maintained under document revision level control by the manufacturer and be made available to the preparing activity (DSCC-VA) upon request.
- 3.7 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to supply to this drawing. The certificate of compliance (original copy) submitted to DSCC-VA shall affirm that the manufacturer's product meets the performance requirements of MIL-PRF-38534 and herein.
- 3.8 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38534 shall be provided with each lot of microcircuits delivered to this drawing.

4. QUALITY ASSURANCE PROVISIONS

4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38534 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

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		TABLE I. Electrical perform	ance characte	eristics.			
Test	Symbol	Conditions <u>1</u> / -55°C ≤ T _C ≤ +125°C V _{CC} = 0 V dc	Group A subgroups	Device types	Limits		Unit
		VSS = 0 V dc +4.5 V dc ≤ V _{CC} ≤ +5.5 V dc unless otherwise specified			Min	Max	1
DC PARAMETERS							
Supply current	lcc	CS = V _{IL} , OE = V _{IH} , f = 5 MHz, CMOS compatible, V _{CC} = +5.5 V dc	1, 2, 3	01, 02 03 04 05 06- 09		70 80 120 165 210	mA
Standby current	I _{SB}	CS = V _{CC} , OE = V _{IH} , f = 5 MHz, CMOS compatible, V _{CC} = +5.5 V dc	1, 2, 3	01, 02 03 04 05 06 07, 08		2.5 4.0 45 50 55 60 80	mA
input leakage current	ILI	$V_{CC} = +5.5 \text{ V dc}, V_{IN} = \text{GND}$	1, 2, 3	All		15	μΑ
Output leakage current	I _{LO}	CS = OE = V _{IH} , V _{OUT} = GND to V _{CC}	1, 2, 3	All		15	μА
Input low voltage	v _{IL}		1, 2, 3	All		0.8	V
Input high voltage	V _{IH}		1, 2, 3	All	2.2		V
Output low voltage	v _{OL}	Device types 01 through 05, I _{OL} = 2.1 mA	1, 2, 3	All		0.4	V
		Device types 06 through 09, I _{OL} = 8.0 mA					
Output high voltage	v _{OH}	Device types 01 through 05, IOH = -1.0 mA	1, 2, 3	All	2.4		V
	į	Device types 06 through 09, I _{OH} = -4.0 mA					
See footnotes at end of	table.			1		-	
MICRO	STANDAF		SIZE A				5962-9207
DEFENSE SUF	PPLY CEN	TER COLUMBUS 43216-5000	-	REVISIO	N LEVEL F	SH	IEET 5

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Test	Symbol	Conditions <u>1</u> / -55°C ≤ T _C ≤ +125°C	Group A subgroups	Device types	Limits		Unit	
		V _{SS} = 0 V dc +4.5 V dc ≤ V _{CC} ≤ +5.5 V dc unless otherwise specified	cabgroupe	,ypoo _	Min	Max		
DATA RETENTION	,	ŀ		. ,	1		1	
Data retention supply voltage	v _{DR}	CS ≥ V _{CC} - 0.2 V	1,2,3	All	2.0	5.5	v	
Data retention current 3/	ICCDR	V _{CC} = 3.0 V	1, 2, 3	01, 02 03 04 05 06-09		1.1 1.6 3.0 10.4 12.8	mA	
FUNCTIONAL TESTING	ì	1		1 1			1	
Functional tests		See 4.3.1c	7,8A,8B	All				
READ CYCLE AC TIMIN	۱ <u>Ģ</u>							
Input capacitance 2/	C ^{IN}	V _{IN} = 0 V dc, f = 1 MHz	4	01 - 05		40	pF	
Output capacitance 2/	C _{OUT}	V _{OUT} = 0 V dc, f = 1 MHz	4	06 - 09		45 40	pF	
				06 - 09		45		
Read cycle time	^t RC	See figure 4	9,10,11	01 02 03 04 05 06 07 08 09	120 100 85 70 55 45 35 25		ns	
Address access time	^t AA	See figure 4	9,10,11	01 02 03 04 05 06 07 08 09		120 100 85 70 55 45 35 25	ns	
See footnotes at end of	table.							
MICRO	STANDAR		SIZE A			59	62-9207	
MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000				REVISION	N LEVEL	SHEI	ET	

Test	Symbol	Conditions 1/	Group A	Device	Limit		Unit
		-55°C ≤ T _C ≤ +125°C V _{SS} = 0 V dc +4.5 V dc ≤ V _{CC} ≤ +5.5 V dc unless otherwise specified	subgroups	types	Min	Max	- Orin
READ CYCLE AC TIMII	NG - Continu	ued.					
Chip select access time	^t ACS	See figure 4	9,10,11	01 02 03 04 05 06 07 08 09		120 100 85 70 55 45 35 25	ns
Output hold from address change	t _{OH}	See figure 4	9,10,11	01-03	15		ns
				04	5		_
	_			05 - 08	3		
Chip select to output in low impedance	tCLZ	See figure 4	9,10,11	01-03	10		_ ns
				04, 05	5		_
				06 - 09	3		
Chip select to output in high impedance	^t CHZ	See figure 4	9,10,11	01, 02 03 04 05 06 07 08 09		50 45 40 35 30 20 17	ns
Output enable to output valid	^t OE	See figure 4	9,10,11	01, 02 03 04 05 06 07 08, 09		60 55 50 40 35 25	ns
Output enable to output in low impedance	t _{OLZ}	See figure 4	9,10,11	01 - 04 05 - 09	5.0 0	11111	_ ns
See footnotes at end of	STANDAF	•	SIZE A			5	962-9207
MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000				REVISIO	N LEVEL F		EET 7

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	1	1	1	1 1			1
Test	Symbol	Conditions 1/ -55°C \leq T _C \leq +125°C V _{SS} = 0 V dc +4.5 V dc \leq V _{CC} \leq +5.5 V dc unless otherwise specified	Group A subgroups	Device types	Limi	ts	Unit
		unless otherwise specified			Min	Max	
READ CYCLE AC TIM	ING - Continu	ued.					
Output enable to output in high impedance	^t OHZ	See figure 4	9,10,11	01, 02 03 04 05 06 07 08 09		50 45 40 30 25 20 15 12	ns
WRITE CYCLE AC TIN	<u>/ING</u>	1	1	<u> </u>			1
Address setup time	^t AS	See figure 5	9,10,11	All	2	: 	ns
Write cycle time	^t wc	See figure 5	9,10,11	01 02 03 04 05 06 07 08 09	120 100 85 70 55 45 35 25		ns
Write pulse width	t _{WP}	See figure 5	9,10,11	01 02 03 04, 05 06 07 08 09	80 70 65 40 30 25 20		ns
Write recovery time	twR	See figure 5	9,10,11	All	2		ns
See footnotes at end o	f table.						
	STANDAD		SIZE				
	STANDAR	i i	Α	1		59	62-920
	OCIRCUIT D	ER COLUMBUS					

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	TA	BLE I. Electrical performance of	haracteristics	- Continue	ed.		
Test	Symbol	Conditions <u>1</u> / -55°C ≤ T _C ≤ +125°C	Group A subgroups	Device types	Limits		Unit
		-55° C ≤ T _C ≤ +125°C V _{SS} = 0 V dc +4.5 V dc ≤ V _{CC} ≤ +5.5 V dc unless otherwise specified			Min	Max	
WRITE CYCLE AC TIMI	NG - Contir	nued.					
Data valid to end of write	^t DW	See figure 5	9,10,11	01, 02 03 04 05 06 07 08, 09	50 45 40 30 25 20		ns
Data hold time	^t DH	See figure 5	9,10,11	01 - 04 05 - 09	. 0		ns
Address valid to end of write	t _{AW}	See figure 5	9,10,11	01 02, 03 04, 05 06 07 08	85 75 50 30 25 20		ns

 $\underline{1}/$ Unless otherwise specified; the AC test conditions are as follows: Input pulse levels: $V_{|L}=0$ V and $V_{|H}=3.0$ V. Input rise and fall times: 5 nanoseconds Input and output timing reference levels: 1.5 V.

Unless otherwise specified; the DC test conditions are as follows: VIH = VCC - 0.3 V. VIL = 0.3 V. Output loading: See figure 7.

$$V_{IH} = V_{CC} - 0.3 \text{ V}$$

 $V_{II} = 0.3 \text{ V}$.

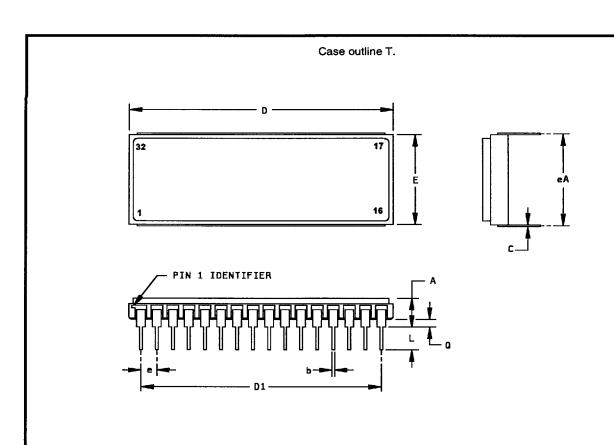
Parameters shall be tested as part of device characterization and after design and process changes. Parameters shall be guaranteed to the limits specified in table I for all lots not specifically tested.

For device types 01 and 02, the maximum limit for data retention current is 200 µA at +70°C.

SIZE **STANDARD** Α 5962-92078 **MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS REVISION LEVEL** SHEET **COLUMBUS, OHIO 43216-5000** 9

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l Symboll	Millim	neters	l I Inch	es l
!!!			!!	!
[<u></u>	Min I	Max	<u>l Min l</u>	<u>Max</u> l
l <u> A I</u>	3.56 I	5.13	l 0.140 l	0.202
l <u>b l</u>	0.41	0.51	i 0.016 l	0.020 I
<u> </u>	0.20	0.30	0.009 1	0.012
l D I	42.01	42.82	l 1.654 l	1.686
l <u>D1</u>	37.90 I	38.30	l 1.492 l	1.508
E	14.73 l	15.34	0.580 I	0.604 l
e l	2.5	50 BSC	0.100	BSC I
l <u>e</u> A l	14.99 l	15.49	0.590	0.610
l <u> </u>	3.18 I	4.90	0.125 I	0.193
Q	0.48 l	1.19	l 0.019 l	0.047

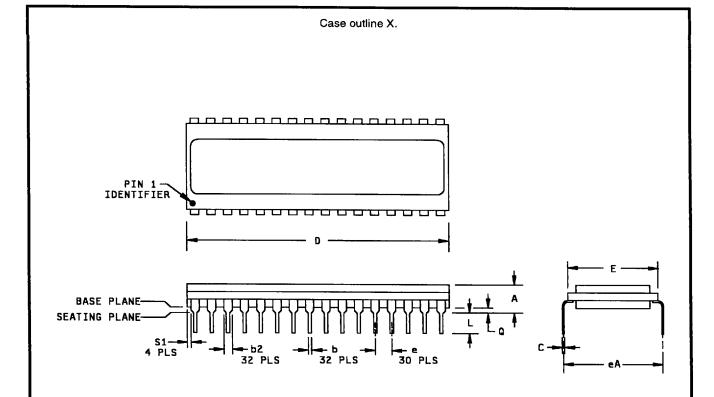
- The U.S. preferred system of measurement is the metric SI. This item was designed using inch-pound units of measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units shall rule.
- 2. Pin numbers are for reference only.

FIGURE 1. Case outline(s).

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Symbol	Millim	eters	Incl	nes
	Min	Max	Min	Max
A	3.68	5.08	0.145	0.200
b	0.41	0.51	0.016	0.020
b2	1.14	1.40	0.045	0.055
C	0.23	0.30	0.009	0.012
D	40.23	41.05	1.584	1.616
E	13.77	14.17	0.542	0.558
е	2.54	BSC	0.100	BSC
eA	14.99	15.49	0.590	0.610
L	3.18		0.125	
Q	0.64	1.52	0.025	0.060
<u>S1</u>	0.13		0.005	

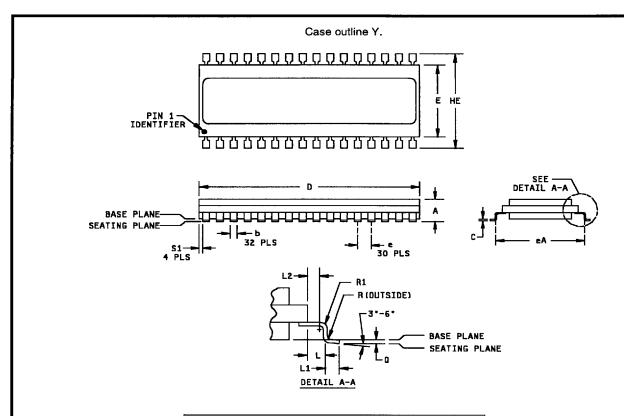
The U.S. preferred system of measurement is the metric SI. This item was designed using inch-pound units of
measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units
shall rule.

FIGURE 1. Case outline(s) - Continued.

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DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
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Symbol	Millimeters		Inc	nes
	Min	Max	Min	Max
Α	3.35	4.29	0.132	0.169
b	1.14	1.40	0.045	0.055
С	0.23	0.30	0.009	0.012
D	40.23	41.05	1.584	1.616
E	13.81	14.12	0.544	0.556
HE	17.91	18.42	0.705	0.725
е	2.54 B	SC	0.100 BSC	
eA	15.67	16.59	0.617	0.653
L	1.079	TYP	0.0425 TYP	
L1	1.02	1.27	0.040	0.050
L2	0.698	TYP	0.0275	TYP
Q	0.08	0.28	0.003	0.011
R	1.02	1.02 TYP		TYP
R1	0.508 TYP		0.020	TYP
S1	0.13	l	0.005	

The U.S. preferred system of measurement is the metric SI. This item was designed using inch-pound units of
measurement. In case of problems involving conflicts between the metric and inch-pound units, the inch-pound units
shall rule.

FIGURE 1. Case outline(s) - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-92078
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
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Device types	01 - 09
Case outlines	All
Terminal number	Terminal connection
1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22	A18 A16 A14 A12 A7 A6 A5 A4 A3 A2 A1 A0 I/O 0 I/O 1 I/O 2 V SS I/O 3 I/O 4 I/O 5 I/O 7 CS
23 24 25 26 27 28	A10 OE A11 A9 A8 A13
29 30 31 32	WE A17 A15 VCC

FIGURE 2. Terminal connections.

_ c s	ŌE	WE	A0-A18	Mode	Data I/O	Device
<u>H</u>	X	Х	X	Standby	High Z	Standby
L	L	H	Stable	Read	Data out	Active
L_	Х	_L	Stable	Write	Data In	Active
L	Н	Н	Stable	Out disable	High Z	Active

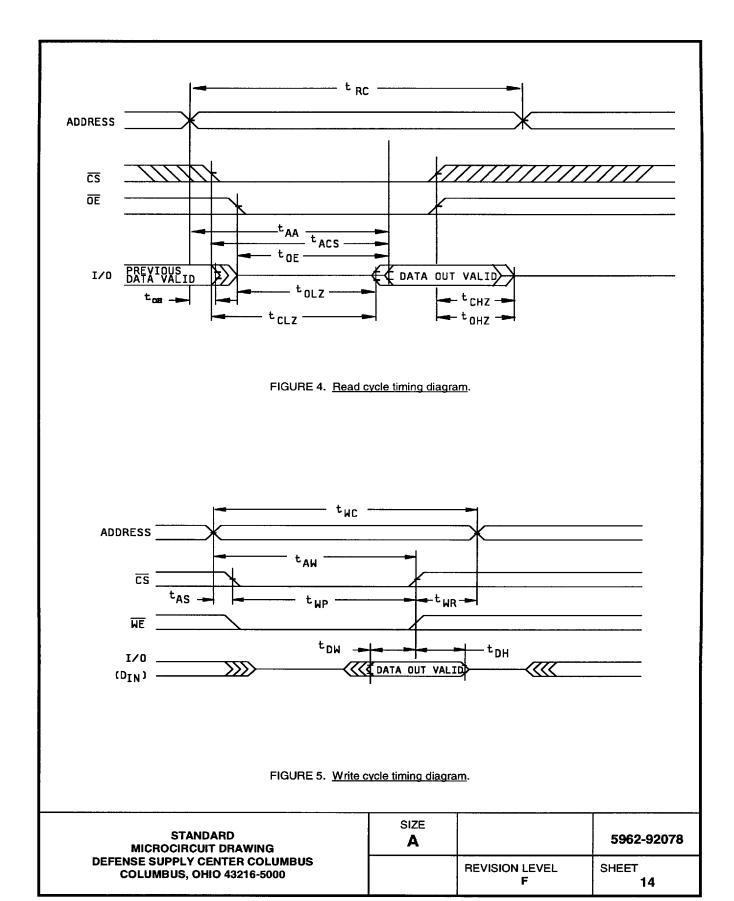
- H = V_{IH} = High logic level
 L = V_{IL} = Low logic level
 X = Do not care (either high or low)
 High Z = High impedance state

FIGURE 3. Truth table.

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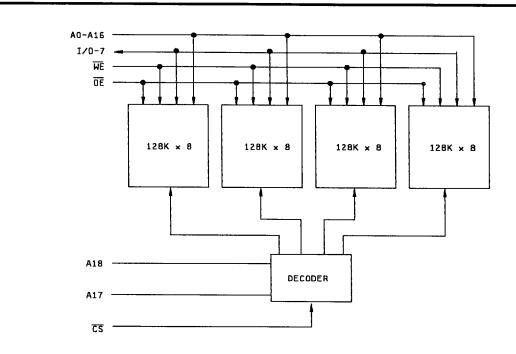
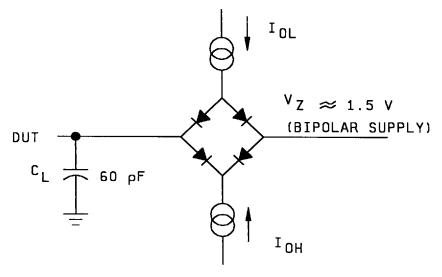


FIGURE 6. Block diagram.



- V_Z is programmable from -2 V to + 7 V. I_{OH} and I_{OL} are programmable from 0 to 16 mA.
 Tester impedance, Z_O = 75 ohms.
 V_Z is typically the midpoint of V_{OH} and V_{OL}, approximately 1.5 V.
 C_L includes tester jig capacitance.

FIGURE 7. Output load circuit.

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TABLE II. Electrical test requirements.

MIL-PRF-38534 test requirements	Subgroups (in accordance with MIL-PRF-38534, group A test table)
Interim electrical parameters	1,4,7,9
Final electrical parameters	1*,2,3,4,7*,8A,8B,9,10, 11
Group A test requirements	1,2,3,4,7,8A,8B,9,10,11
Group C end-point electrical parameters	1,2,3,4,7,8A,8B,9,10,11
MIL-STD-883, group E end-point electrical parameters for RHA devices	Subgroups** (in accordance with method 5005, group A test table)

- * PDA applies to subgroups 1 and 7.
- ** When applicable to this standard microcircuit drawing, the subgroups shall be defined.
- 4.2 Screening. Screening shall be in accordance with MIL-PRF-38534. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition B. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to either DSCC-VA or the acquiring activity upon request. Also, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - (2) T_A as specified in accordance with table I of method 1015 of MIL-STD-883.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 <u>Conformance and periodic inspections</u>. Conformance inspection (CI) and periodic inspection (PI) shall be in accordance with MIL-PRF-38534 and as specified herein.
 - 4.3.1 Group A inspection (CI). Group A inspection shall be in accordance with MIL-PRF-38534 and as follows:
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 5 and 6 shall be omitted.
 - c. Subgroups 7, 8A, and 8B shall include verification of the truth table on figure 3.
 - 4.3.2 Group B inspection (PI). Group B inspection shall be in accordance with MIL-PRF-38534.

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- 4.3.3 Group C inspection (PI). Group C inspection shall be in accordance with MIL-PRF-38534 and as follows:
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test, method 1005 of MIL-STD-883.
 - (1) Test condition B. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to either DSCC-VA or the acquiring activity upon request. Also, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
 - (2) T_A as specified in accordance with table I of method 1005 of MIL-STD-883.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- 4.3.4 Group D inspection (PI). Group D inspection shall be in accordance with MIL-PRF-38534.
- 4.3.5 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels shall be M, D, R, and H. RHA quality conformance inspection sample tests shall be performed at the RHA level specified in the acquisition document.
 - a. RHA tests for levels M, D, R, and H shall be performed through each level to determine at what levels the devices meet the RHA requirements. These RHA tests shall be performed for initial qualification and after design or process changes which may affect the RHA performance of the device.
 - b. End-point electrical parameters shall be as specified in table II herein.
 - c. Prior to total dose irradiation, each selected sample shall be assembled in its qualified package. It shall pass the specified group A electrical parameters in table I for subgroups specified in table II herein.
 - d. The devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38534 for RHA level being tested, and meet the postirradiation end-point electrical parameter limits as defined in table I at T_A = +25°C ±5 percent, after exposure.
 - e. Prior to and during total dose irradiation testing, the devices shall be biased to establish a worst case condition as specified in the radiation exposure circuit.
 - For device classes H and K, subgroups 1 and 2 in table V, method 5005 of MIL-STD-883 shall be tested as appropriate for device construction.
 - g. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.
 - 5. PACKAGING
 - 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38534.

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6. NOTES

- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.
- 6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Supply Center Columbus when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0526.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43216-5000, or telephone (614) 692-0512.
- 6.6 <u>Sources of supply</u>. Sources of supply are listed in QML-38534. The vendors listed in QML-38534 have submitted a certificate of compliance (see 3.7 herein) to DSCC-VA and have agreed to this drawing.

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STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN

DATE: 98-06-23

Approved sources of supply for SMD 5962-92078 are listed below for immediate acquisition only and shall be added to QML-38534 during the next revision. QML-38534 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This bulletin is superseded by the next dated revision of QML-38534.

Standard	Vendor	Vendor
microcircuit drawing	CAGE	similar
PIN 1/	number	PIN <u>2</u> /
5962-9207801HTX	54230	WS512K8-120CQ
5962-9207801HXX	54230	WS512K8-120CQ
5962-9207801HYX	54230	WS512K8-120CLQ
5962-9207802HTX	54230	WS512K8-100CQ
5962-9207802HXX	54230	WS512K8-100CQ
5962-9207802HYX	54230	WS512K8-100CLQ
5962-9207803HTX	54230	WS512K8-85CQ
5962-9207803HXX	54230	WS512K8-85CQ
5962-9207803HYX	54230	WS512K8-85CLQ
5962-9207804HTX	54230	WS512K8-70CQ
5962-9207804HXX	54230	WS512K8-70CQ
5962-9207804HYX	54230	WS512K8-70CLQ
5962-9207805HTX	54230	WS512K8-55CQ
5962-9207805HXX	54230	WS512K8-55CQ
5962-9207805HYX	54230	WS512K8-55CLQ
5962-9207806HTX	54230	WS512K8-45CQ
5962-9207806HXX	54230	WS512K8-45CQ
5962-9207806HYX	54230	WS512K8-45CLQ
5962-9207807HTX	54230	WS512K8-35CQ
5962-9207807HXX	54230	WS512K8-35CQ
5962-9207807HYX	54230	WS512K8-35CLQ

^{1/} The lead finish shown for each PIN representing a hermetic package is available in lead finishes A or C from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.

2/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

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STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN - Continued.

DATE: 98-06-23

Standard	Vendor	Vendor
microcircuit drawing	CAGE	similar
PIN <u>1</u> /	number	PIN <u>2</u> /
5962-9207808HTX	54230	WS512K8-25CQ
5962-9207808HXX	54230	WS512K8-25CQ
5962-9207808HYX	54230	WS512K8-25CLQ
5962-9207809HTX	54230	WS512K8-20CQ
5962-9207809HXX	54230	WS512K8-20CQ
5962-9207809HYX	54230	WS512K8-20CLQ

- The lead finish shown for each PIN representing a hermetic package is available in lead finishes A or C from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availibility.
- 2/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

54230

Vendor name and address

White Microelectronics 3601 East University Drive Phoenix, AZ 85034

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in this information bulletin.

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